

## 0.35-GHz TO 4-GHz QUADRATURE MODULATORS

Check for Samples: [TRF370315](#), [TRF370333](#)

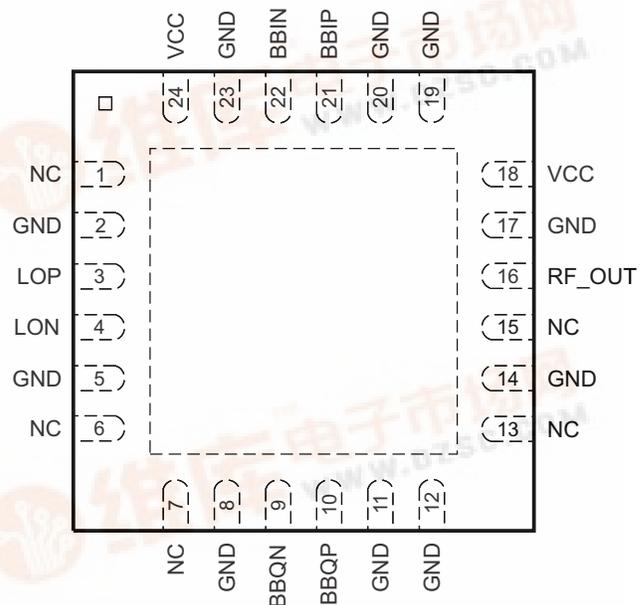
### FEATURES

- 75-dBc Single-Carrier WCDMA ACPR at –11-dBm Channel Power
- Low Noise Floor: –163 dBm/Hz
- OIP3 of 23 dBm
- P1dB of 9 dBm
- Unadjusted Carrier Feedthrough of –40 dBm
- Unadjusted Side-Band Suppression of –40 dBc
- Single Supply: 4.5 V–5.5 V Operation
- Silicon Germanium Technology
- TRF370333 With 3.3-V CM at I, Q Baseband Inputs
- TRF370315 With 1.5-V CM at I, Q Baseband Inputs

### APPLICATIONS

- Cellular Base Transceiver Station Transmit Channel
- CDMA: IS95, UMTS, CDMA2000, TD-SCDMA
- TDMA: GSM, IS-136, EDGE/UWC-136
- Wireless Local Loop
- Wireless MAN Wideband Transceivers

RGE PACKAGE  
(TOP VIEW)



P0024-04

### DESCRIPTION

The TRF370315 and TRF370333 are low-noise direct quadrature modulators, capable of converting complex modulated signals from baseband or IF directly up to RF. The TRF370315 and TRF370333 are ideal for high-performance direct RF modulation from 350 MHz up to 4 GHz. These modulators are implemented as a double-balanced mixer. The RF output block consists of a differential to single-ended converter and an RF amplifier capable of driving a single-ended 50-Ω load without any need of external components. The TRF370333 and TRF370315 devices have different common-mode voltage ratings at the I/Q baseband inputs. The TRF370315 requires a 1.5-V common-mode voltage, and the TRF370333 requires a 3.3-V common-mode voltage.



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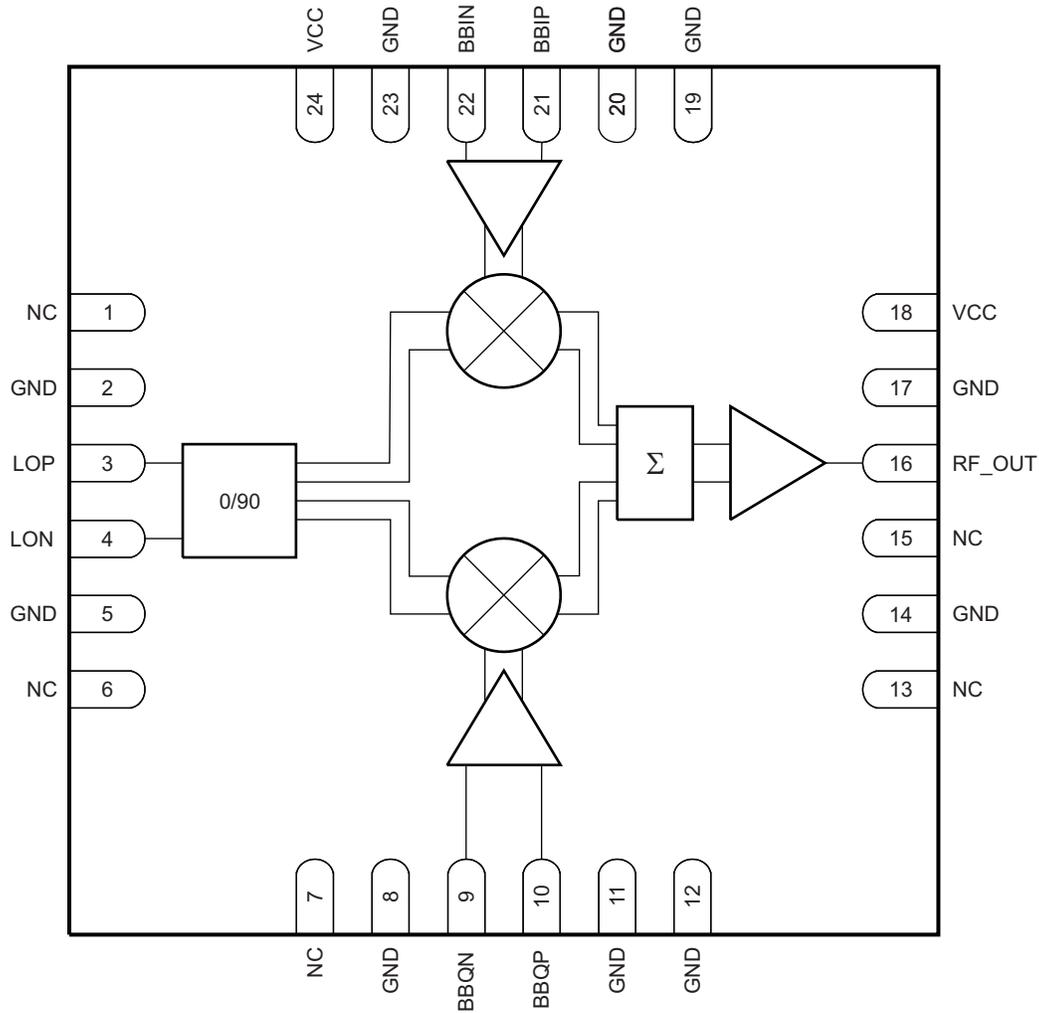




This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

## FUNCTIONAL BLOCK DIAGRAM



B0175-01

NOTE: NC = No connection

**DEVICE INFORMATION**
**TERMINAL FUNCTIONS**

TERMINAL		I/O	DESCRIPTION
NAME	NO.		
BBIN	22	I	In-phase input
BBIP	21	I	In-phase input
BBQN	9	I	In-quadrature input
BBQP	10	I	In-quadrature input
GND	2, 5, 8, 11, 12, 14, 17, 19, 20, 23	–	Ground
LON	4	I	Local oscillator input
LOP	3	I	Local oscillator input
NC	1, 6, 7, 13, 15	–	No connect
RF_OUT	16	O	RF output
VCC	18, 24	–	Power supply

**ABSOLUTE MAXIMUM RATINGS<sup>(1)</sup>**

Over operating free-air temperature range (unless otherwise noted).

		VALUE <sup>(2)</sup>	UNIT	
Supply voltage range		–0.3 V to 6	V	
Digital I/O voltage range		–0.3 V to $V_I + 0.3$	V	
$T_J$	Operating virtual junction temperature range	–40 to 150	°C	
$T_A$	Operating ambient temperature range	–40 to 85	°C	
$T_{stg}$	Storage temperature range	–65 to 150	°C	
ESD	Electrostatic discharge ratings	Human body model (HBM)	75	V
		Charged device model (CDM)	75	V

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values are with respect to network ground terminal.

**RECOMMENDED OPERATING CONDITIONS**

Over operating free-air temperature range (unless otherwise noted).

		MIN	NOM	MAX	UNIT
$V_{CC}$	Power-supply voltage	4.5	5	5.5	V

**THERMAL CHARACTERISTICS**

PARAMETER		TEST CONDITIONS	VALUE	UNIT
$R_{\theta JA}$	Thermal resistance, junction-to-ambient	High-K board, still air	29.4	°C/W
$R_{\theta JC}$	Thermal resistance, junction-to-case		18.6	°C/W

## ELECTRICAL CHARACTERISTICS

Over operating free-air temperature range (unless otherwise noted).

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>DC Parameters</b>						
I <sub>CC</sub>	Total supply current (1.5 V CM)	T <sub>A</sub> = 25°C		195	205	mA
	Total supply current (3.3 V CM)	T <sub>A</sub> = 25°C		210	235	
<b>LO Input (50-Ω, Single-Ended)</b>						
f <sub>LO</sub>	LO frequency range		0.35		4	GHz
	LO input power		-5	0	12	dBm
	LO port return loss			15		dB
<b>Baseband Inputs</b>						
V <sub>CM</sub>	I and Q input dc common voltage	TRF370333		3.3		V
		TRF370315		1.5		
BW	1-dB input frequency bandwidth		350			MHz
Z <sub>I(single ended)</sub>	Input impedance, resistance	TRF370333		10		kΩ
	Input impedance, parallel capacitance			3		pF
	Input impedance, resistance	TRF370315		5		kΩ
	Input impedance, parallel capacitance			3		pF

## ELECTRICAL CHARACTERISTICS

Over recommended operating conditions, power supply = 5 V, T<sub>A</sub> = 25°C, f<sub>LO</sub> = **350 MHz** at 0 dBm, TRF370333 (unless otherwise noted).

<b>RF Output Parameters</b>						
PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
G	Voltage gain	Output rms voltage over input I (or Q) rms voltage		-2.2		dB
P1dB	Output compression point			9.4		dBm
IP3	Output IP3			24.5		dBm
IP2	Output IP2	Measured at f <sub>LO</sub> + 2 × f <sub>BB</sub>		73.8		dBm
	Carrier feedthrough	Unadjusted		35.6		dBm
	Sideband suppression	Unadjusted		33.8		dBc
Output noise floor	DC only to BB inputs, 13 MHz offset from f <sub>LO</sub>			-158.0		dBm/Hz
	1.8-MHz offset from f <sub>LO</sub> ; 1 CW tone; P <sub>out</sub> = 0 dBm			-152.6		
	6-MHz offset from f <sub>LO</sub> ; 1 CW tone; P <sub>out</sub> = 0 dBm			-157.4		

## ELECTRICAL CHARACTERISTICS

Over recommended operating conditions, power supply = 5 V, T<sub>A</sub> = 25°C, f<sub>LO</sub> = **400 MHz** at 0 dBm, TRF370315 (unless otherwise noted).

<b>RF Output Parameters</b>						
PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
G	Voltage gain	Output rms voltage over input I (or Q) rms voltage		-2.3		dB
P1dB	Output compression point			9.4		dBm
IP3	Output IP3		20	23		dBm
IP2	Output IP2	Measured at f <sub>LO</sub> + 2 × f <sub>BB</sub>		62		dBm
	Carrier feedthrough	Unadjusted		-37		dBm
	Sideband suppression	Unadjusted		-39		dBc

## ELECTRICAL CHARACTERISTICS

Over recommended operating conditions, power supply = 5 V,  $T_A = 25^\circ\text{C}$ ,  $f_{LO} = 900\text{ MHz}$  at 0 dBm, TRF370315 (unless otherwise noted).

RF Output Parameters					
PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
G	Voltage gain	Output rms voltage over input I (or Q) rms voltage		-4.1	dB
P1dB	Output compression point			9	dBm
IP3	Output IP3	20	23		dBm
IP2	Output IP2	Measured at $f_{LO} + 2 \times f_{BB}$		63	dBm
	Carrier feedthrough	Unadjusted		-37	dBm
	Sideband suppression	Unadjusted		-42	dBc
	Output return loss			9	dB
	Output noise floor	DC only to BB inputs, 13 MHz offset from $f_{LO}$		-160.4	dBm/Hz
		1.8-MHz offset from $f_{LO}$ ; 1 CW tone; $P_{out} = 0\text{ dBm}$		-156.6	
		6-MHz offset from $f_{LO}$ ; 1 CW tone; $P_{out} = 0\text{ dBm}$		-158.5	
EVM	Error vector magnitude (rms)	1 EDGE signal, $P_{out} = -5\text{ dBm}$		0.59%	
		1 EDGE signal, $P_{out} = 0\text{ dBm}$		0.63%	
		1 EDGE signal, $P_{out} = 0\text{ dBm}$ , 2nd harmonic of LO = -15 dBm, 3rd harmonic of LO = -33 dBm <sup>(1)</sup>		1%	

(1) The second- and third-harmonic tests were made independently at each frequency.

## ELECTRICAL CHARACTERISTICS

Over recommended operating conditions, power supply = 5 V,  $T_A = 25^\circ\text{C}$ ,  $f_{LO} = 1800\text{ MHz}$  at 0 dBm, TRF370315 (unless otherwise noted).

RF Output Parameters					
PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
G	Voltage gain	Output rms voltage over input I (or Q) rms voltage		-4.4	dB
P1dB	Output compression point			9.5	dBm
IP3	Output IP3	20	23		dBm
IP2	Output IP2	Measured at $f_{LO} + 2 \times f_{BB}$		55	dBm
	Carrier feedthrough	Unadjusted		-40	dBm
	Sideband suppression	Unadjusted		-47	dBc
	Output return loss			8	dB
	Output noise floor	DC only to BB inputs, 13 MHz offset from $f_{LO}$		-162.6	dBm/Hz
		1.8-MHz offset from $f_{LO}$ ; 1 CW tone; $P_{out} = 0\text{ dBm}$		-160	
		6-MHz offset from $f_{LO}$ ; 1 CW tone; $P_{out} = 0\text{ dBm}$		-159.4	
EVM	Error vector magnitude (rms)	1 EDGE signal, $P_{out} = -5\text{ dBm}$		0.66%	
		1 EDGE signal, $P_{out} = 0\text{ dBm}$		0.74%	
		1 EDGE signal, $P_{out} = 0\text{ dBm}$ , 2nd harmonic of LO = -15.5 dBm, 3rd harmonic of LO = -30 dBm <sup>(1)</sup>		1%	

(1) The second- and third-harmonic tests were made independently at each frequency.

[查询 TRF370315 数据手册](#)

## ELECTRICAL CHARACTERISTICS

Over recommended operating conditions, power supply = 5 V,  $T_A = 25^\circ\text{C}$ ,  $f_{LO} = 1960 \text{ MHz}$  at 0 dBm, TRF370315 (unless otherwise noted).

RF Output Parameters						
PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
G	Voltage gain	Output rms voltage over input I (or Q) rms voltage		-4.4		dB
P1dB	Output compression point			9.5		dBm
IP3	Output IP3, TRF370315		20	23		dBm
	Output IP3, TRF370333		18	20		
IP2	Output IP2	Measured at $f_{LO} + 2 \times f_{BB}$		55		dBm
	Carrier feedthrough	Unadjusted		-40		dBm
	Sideband suppression	Unadjusted		-47		dBc
	Output return loss			8		dB
	Output noise floor	DC only to BB inputs, 13 MHz offset from $f_{LO}$		-162.6		dBm/Hz
		1.8-MHz offset from $f_{LO}$ ; 1 CW tone; $P_{out} = 0 \text{ dBm}$		-160		
		6-MHz offset from $f_{LO}$ ; 1 CW tone; $P_{out} = 0 \text{ dBm}$		-159.4		
EVM	Error vector magnitude (rms)	1 EDGE signal, $P_{out} = -5 \text{ dBm}$		0.66%		
		1 EDGE signal, $P_{out} = 0 \text{ dBm}$		0.74%		
		1 EDGE signal, $P_{out} = 0 \text{ dBm}$ , 2nd harmonic of LO = -15.5 dBm, 3rd harmonic of LO = -30 dBm <sup>(1)</sup>		1%		

(1) The second- and third-harmonic tests were made independently at each frequency.

## ELECTRICAL CHARACTERISTICS

Over recommended operating conditions, power supply = 5 V,  $T_A = 25^\circ\text{C}$ ,  $f_{LO} = 2140 \text{ MHz}$  at 0 dBm, TRF370315 (unless otherwise noted).

RF Output Parameters						
PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
G	Voltage gain	Output rms voltage over input I (or Q) rms voltage		-4.5		dB
P1dB	Output compression point			9.5		dBm
IP3	Output IP3, TRF370315		20	23		dBm
	Output IP3, TRF370333		18	21		
IP2	Output IP2	Measured at $f_{LO} + 2 \times f_{BB}$		58		dBm
	Carrier feedthrough	Unadjusted		-40		dBm
	Sideband suppression	Unadjusted		-47		dBc
	Output return loss			8.5		dB
	Output noise floor	20-MHz offset from $f_{LO}$ ; dc only to BB inputs		-163		dBm/Hz
		20-MHz offset from $f_{LO}$ ; 1 WCDMA signal; $P_{in} = -20.5 \text{ dBVrms}$ (I and Q input)		-162		
ACPR	Adjacent-channel power ratio	1 WCDMA signal; $P_{out} = -13 \text{ dBm}$		-75.8		dBc
		1 WCDMA signal; $P_{out} = -9 \text{ dBm}$		-72		
		4 WCDMA signals; $P_{out} = -23 \text{ dBm}$ per carrier		-68		
	Alternate-channel power ratio	1 WCDMA signal; $P_{out} = -13 \text{ dBm}$		-79		dBc
		1 WCDMA signal; $P_{out} = -9 \text{ dBm}$		-80.5		
		4 WCDMA signals; $P_{out} = -23 \text{ dBm}$ per carrier		-69		

## ELECTRICAL CHARACTERISTICS

Over recommended operating conditions, power supply = 5 V,  $T_A = 25^\circ\text{C}$ ,  $f_{LO} = 2500 \text{ MHz}$  at 0 dBm, TRF370315 (unless otherwise noted).

RF Output Parameters					
PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
G	Voltage gain	Output rms voltage over input I (or Q) rms voltage		-4.4	dB
P1dB	Output compression point			9.5	dBm
IP3	Output IP3	18	21		dBm
IP2	Output IP2	Measured at $f_{LO} + 2 \times f_{BB}$		63	dBm
	Carrier feedthrough	Unadjusted		-38	dBm
	Sideband suppression	Unadjusted		-47	dBc

## ELECTRICAL CHARACTERISTICS

Over recommended operating conditions, power supply = 5 V,  $T_A = 25^\circ\text{C}$ ,  $f_{LO} = 3600 \text{ MHz}$  at 0 dBm, TRF370315 (unless otherwise noted).

RF Output Parameters					
PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
G	Voltage gain	Output rms voltage over input I (or Q) rms voltage		-3.5	dB
P1dB	Output compression point			9.5	dBm
IP3	Output IP3	20	23		dBm
IP2	Output IP2	Measured at $f_{LO} + 2 \times f_{BB}$		63	dBm
	Carrier feedthrough	Unadjusted		-41	dBm
	Sideband suppression	Unadjusted		-45	dBc

## ELECTRICAL CHARACTERISTICS

Over recommended operating conditions, power supply = 5 V,  $T_A = 25^\circ\text{C}$ ,  $f_{LO} = 4000 \text{ MHz}$  at 0 dBm, TRF370315 (unless otherwise noted).

RF Output Parameters					
PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
G	Voltage gain	Output rms voltage over input I (or Q) rms voltage		-4.5	dB
P1dB	Output compression point			9	dBm
IP3	Output IP3	19	22		dBm
IP2	Output IP2	Measured at $f_{LO} + 2 \times f_{BB}$		50	dBm
	Carrier feedthrough	Unadjusted		-37	dBm
	Sideband suppression	Unadjusted		-40	dBc

TYPICAL CHARACTERISTICS

OUTPUT POWER  
vs  
BASEBAND VOLTAGE

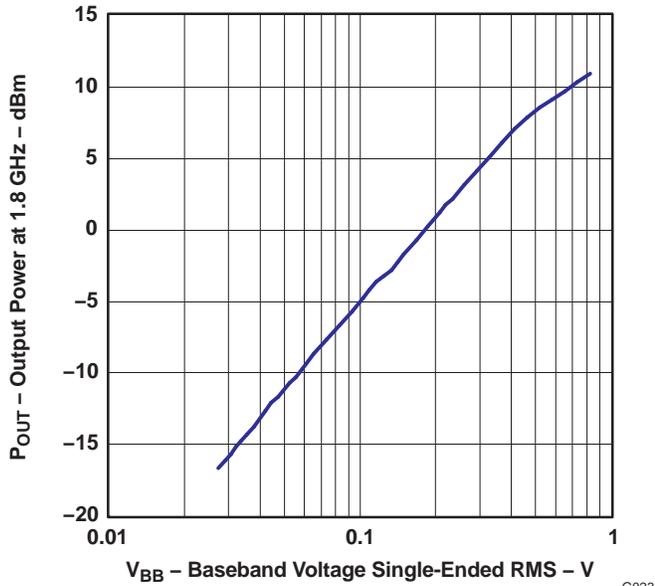


Figure 1.

OUTPUT POWER  
vs  
FREQUENCY AND TEMPERATURE

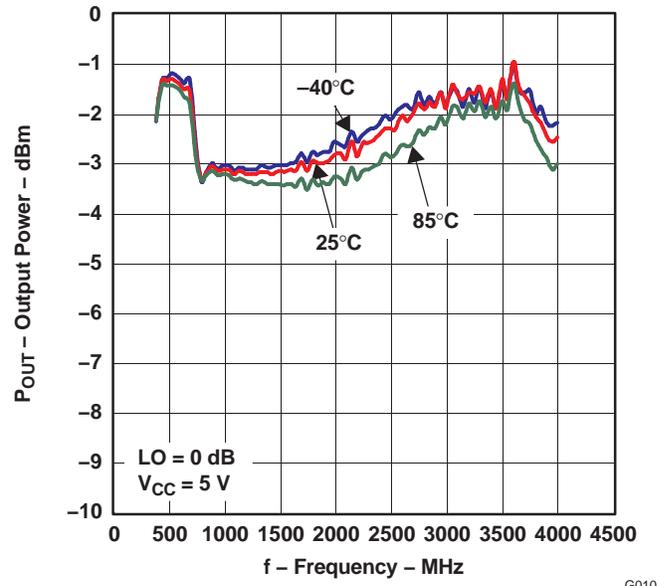


Figure 2.

OUTPUT POWER  
vs  
FREQUENCY AND SUPPLY VOLTAGE

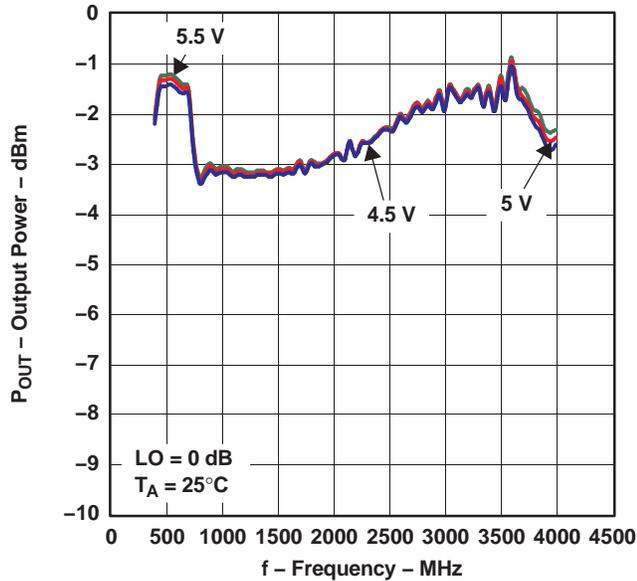


Figure 3.

OUTPUT POWER  
vs  
FREQUENCY AND LO POWER

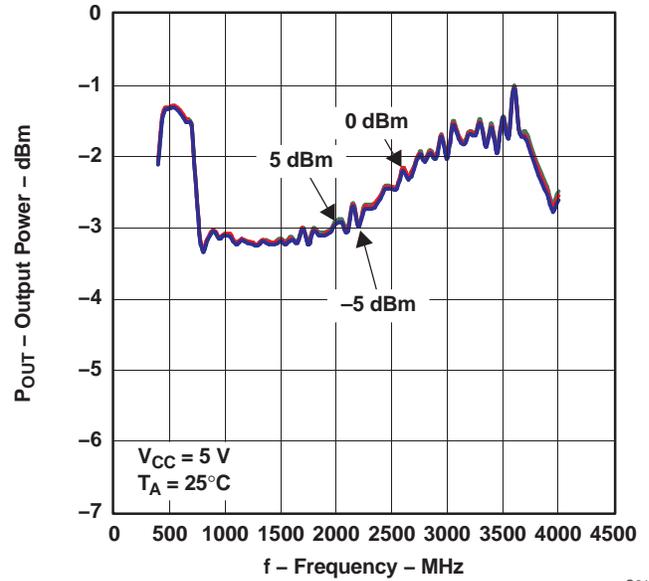


Figure 4.

TYPICAL CHARACTERISTICS (continued)

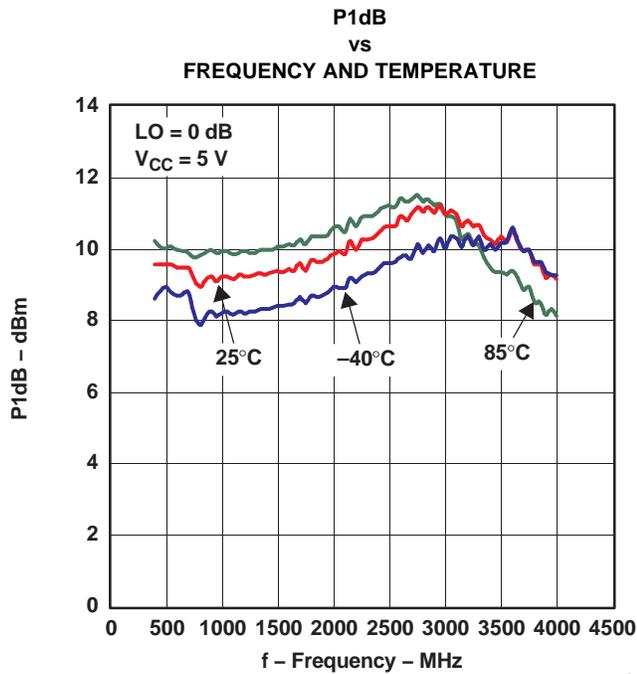


Figure 5.

G001

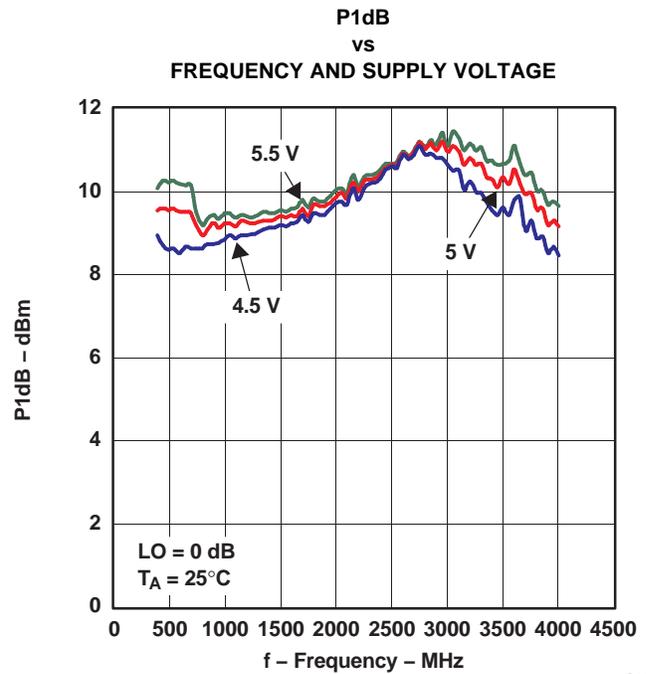


Figure 6.

G002

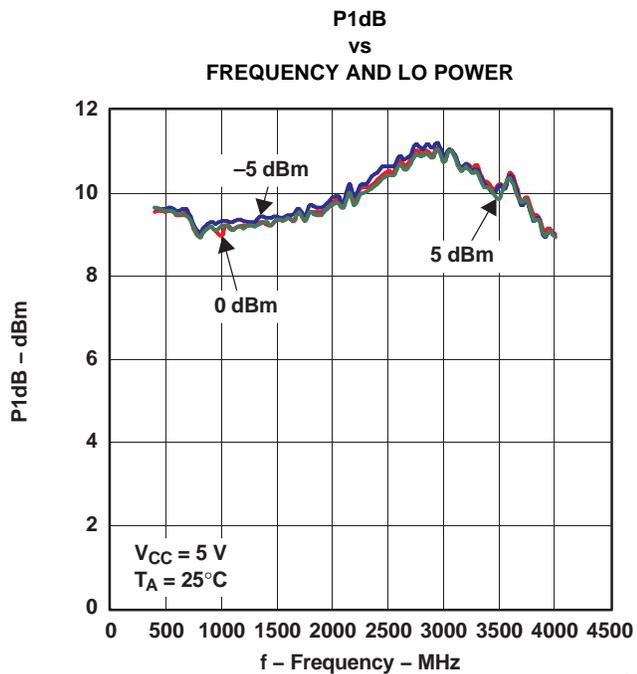


Figure 7.

G003

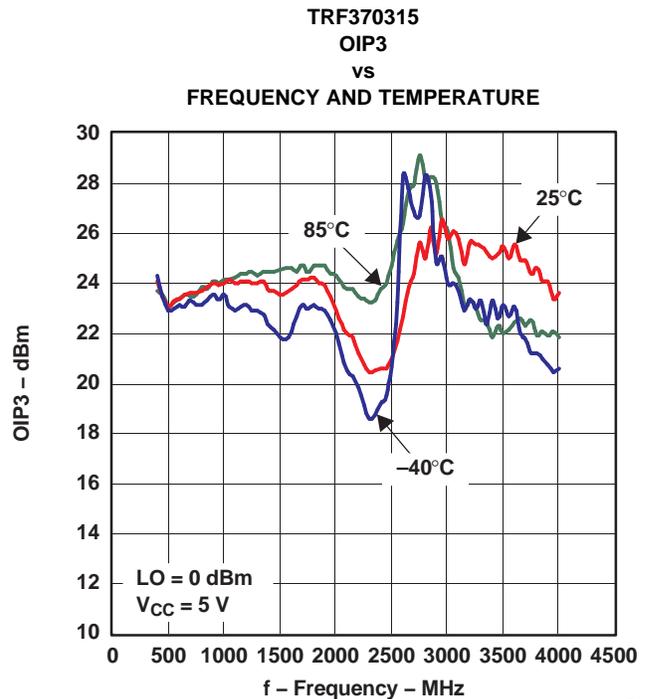


Figure 8.

G014

TYPICAL CHARACTERISTICS (continued)

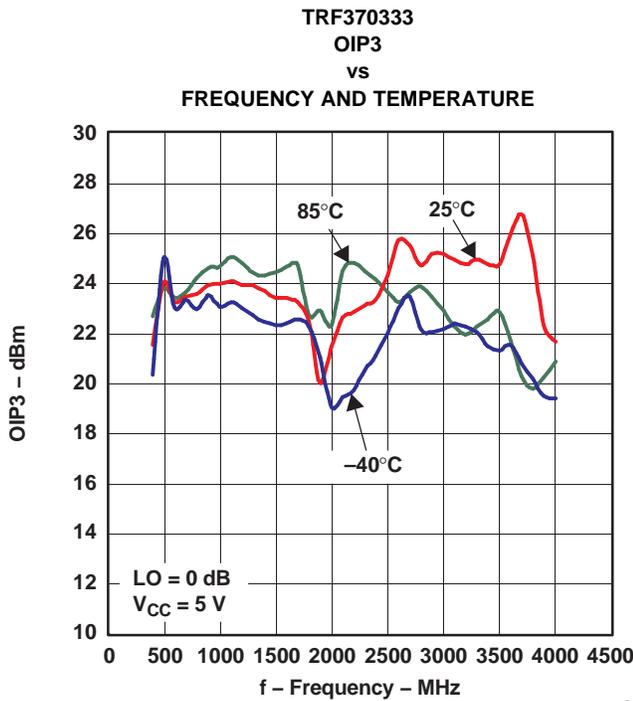


Figure 9.

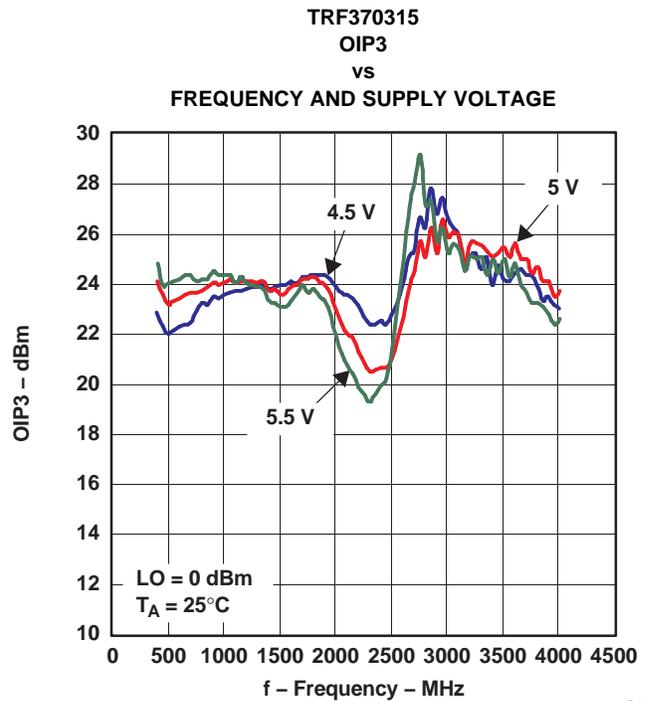


Figure 10.

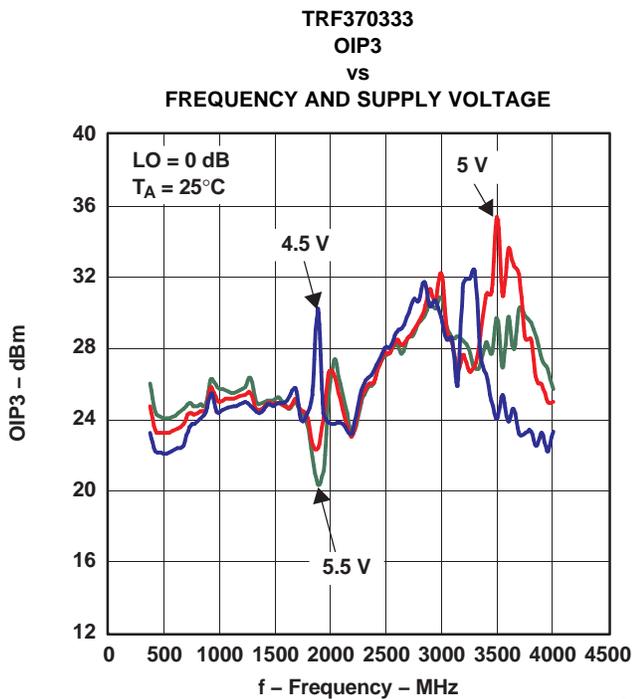


Figure 11.

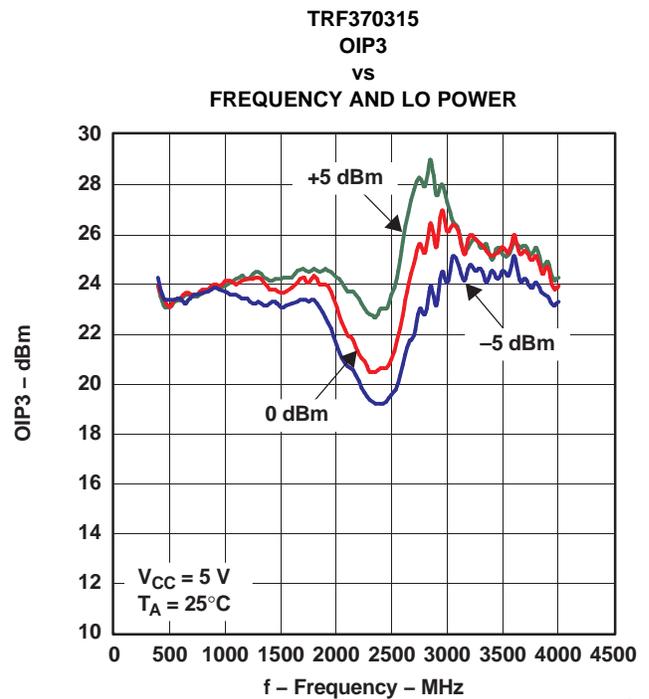


Figure 12.

TYPICAL CHARACTERISTICS (continued)

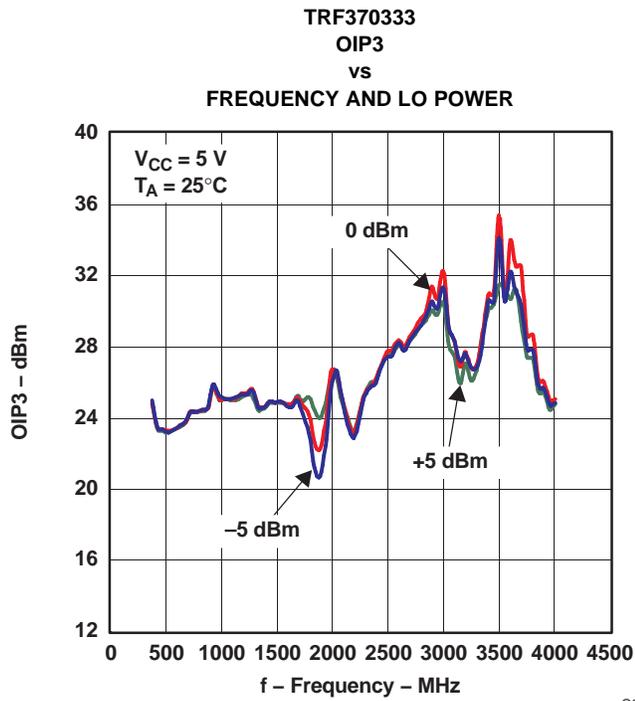


Figure 13.

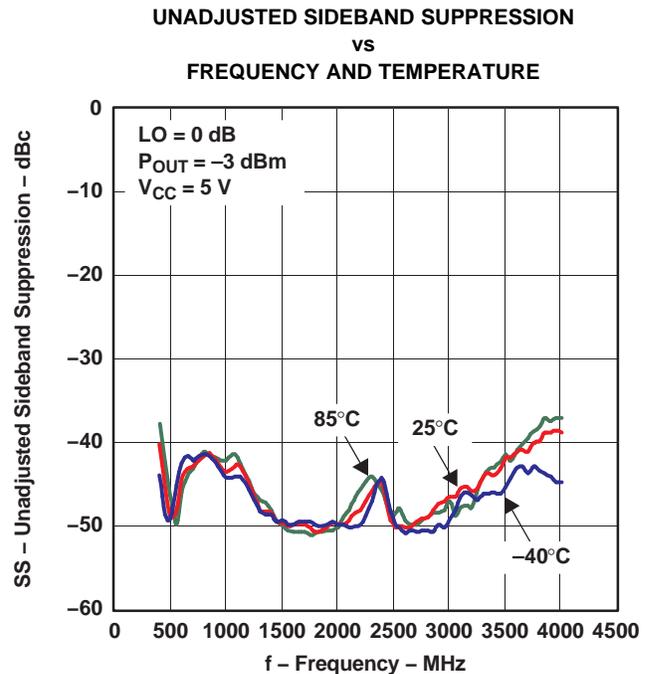


Figure 14.

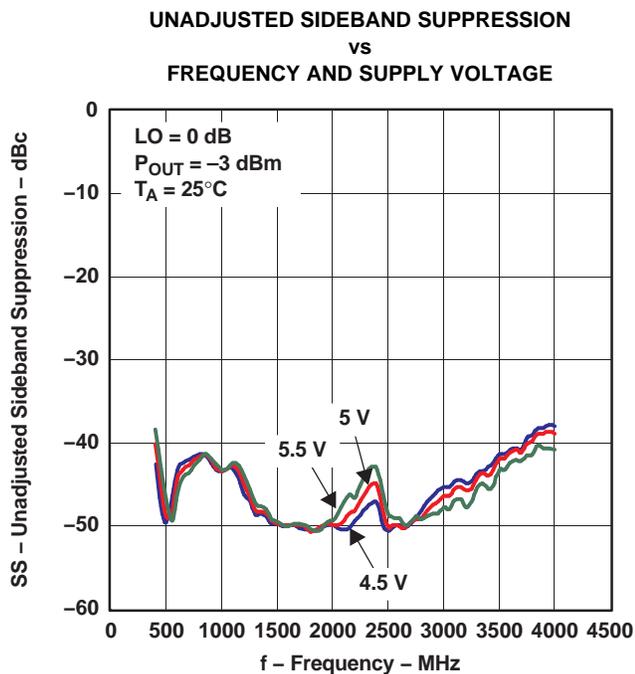


Figure 15.

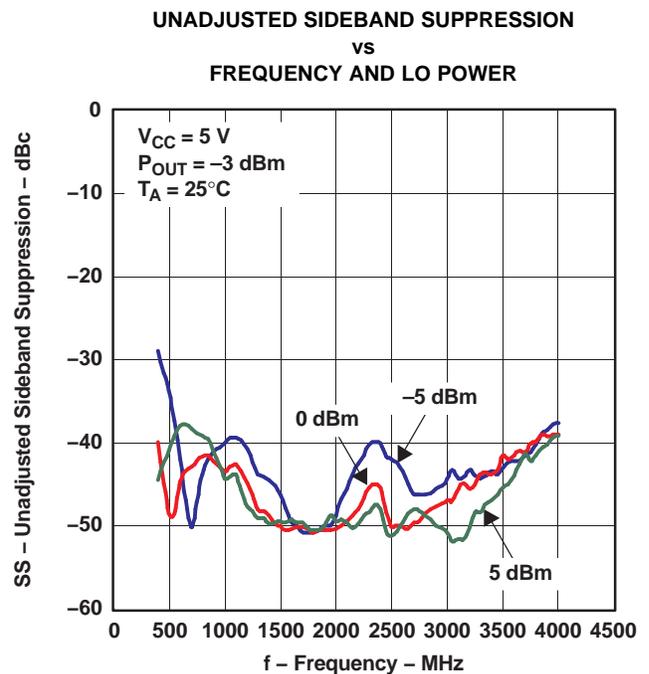


Figure 16.

TYPICAL CHARACTERISTICS (continued)

ADJUSTED SIDEBAND SUPPRESSION  
vs  
FREQUENCY AND TEMPERATURE

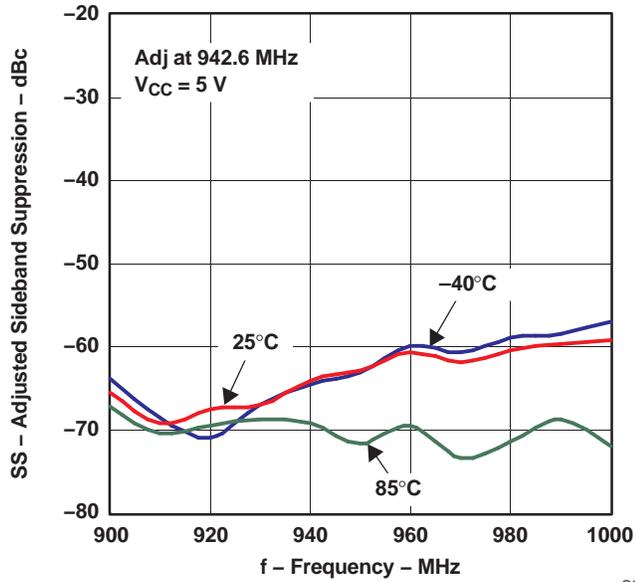


Figure 17.

G016

ADJUSTED SIDEBAND SUPPRESSION  
vs  
FREQUENCY AND TEMPERATURE

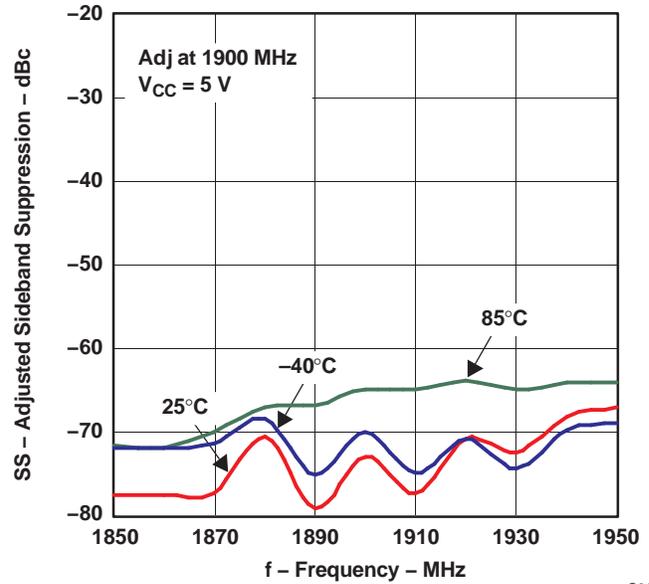


Figure 18.

G017

ADJUSTED SIDEBAND SUPPRESSION  
vs  
FREQUENCY AND TEMPERATURE

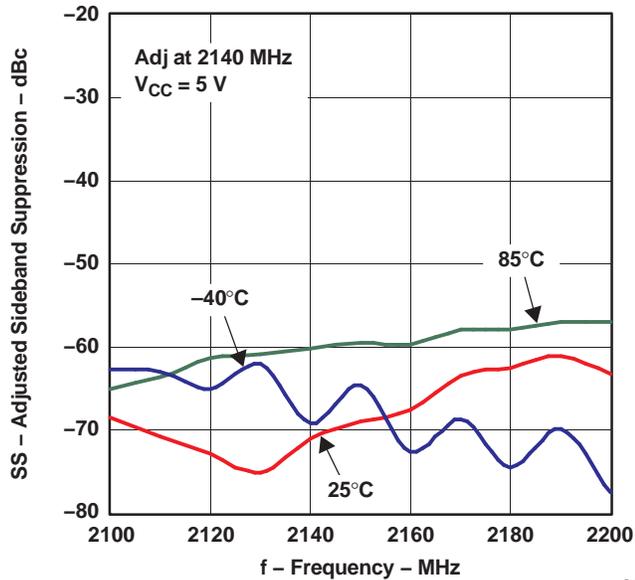


Figure 19.

G018

NOISE AT 13-MHz OFFSET (dBm/Hz)  
vs  
FREQUENCY AND SUPPLY VOLTAGE

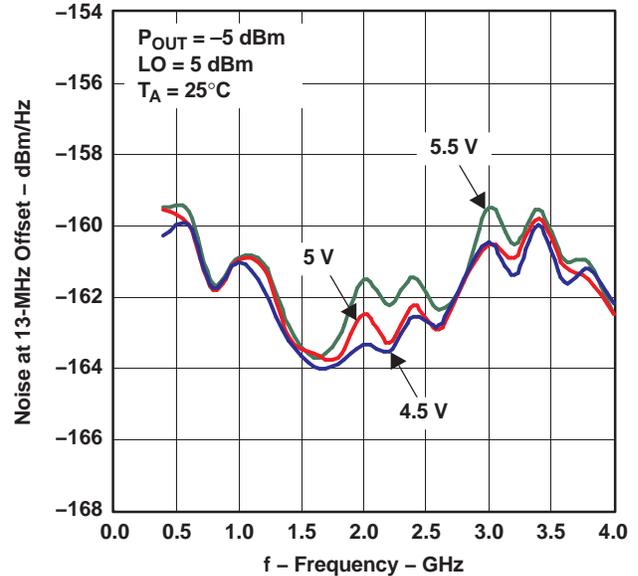


Figure 20.

G019

TYPICAL CHARACTERISTICS (continued)

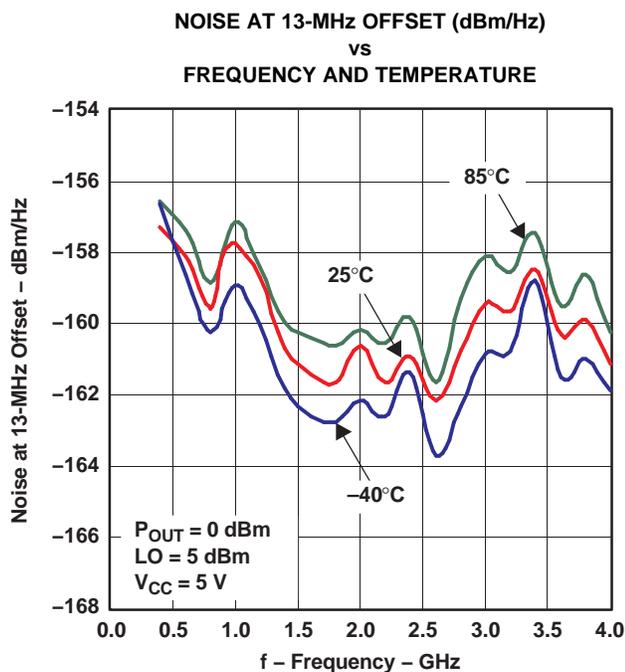


Figure 21.

G020

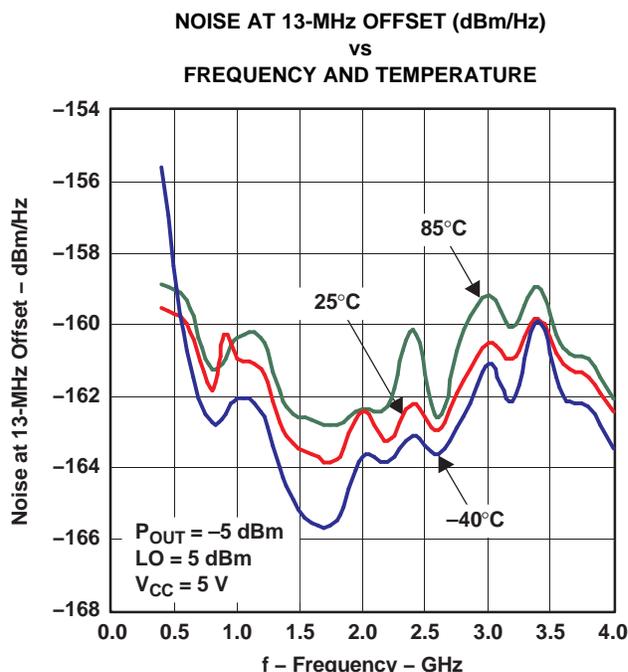


Figure 22.

G021

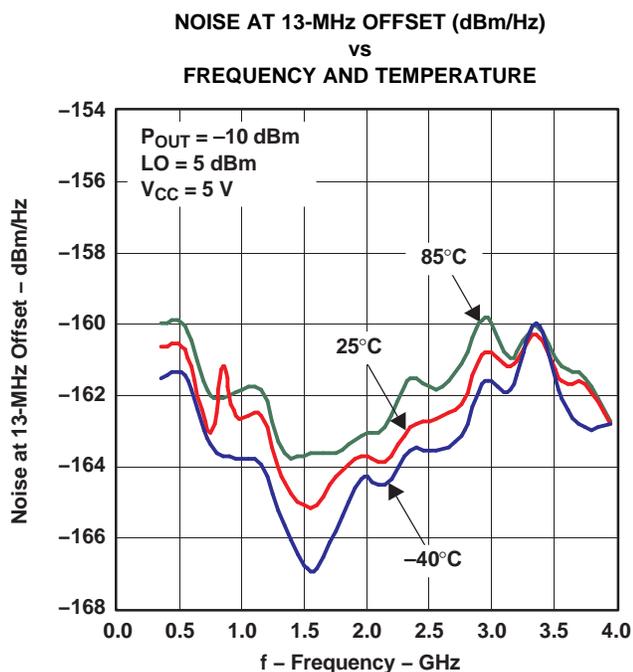


Figure 23.

G022

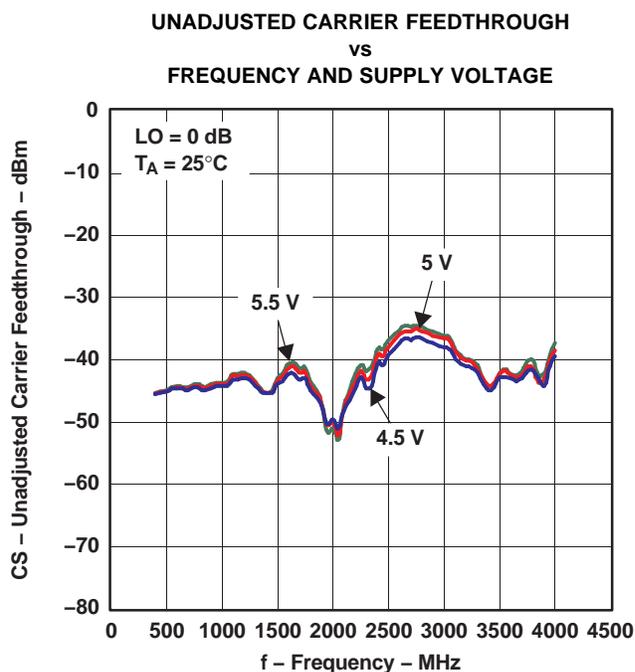


Figure 24.

G025

### TYPICAL CHARACTERISTICS (continued)

UNADJUSTED CARRIER FEEDTHROUGH  
vs  
FREQUENCY AND TEMPERATURE

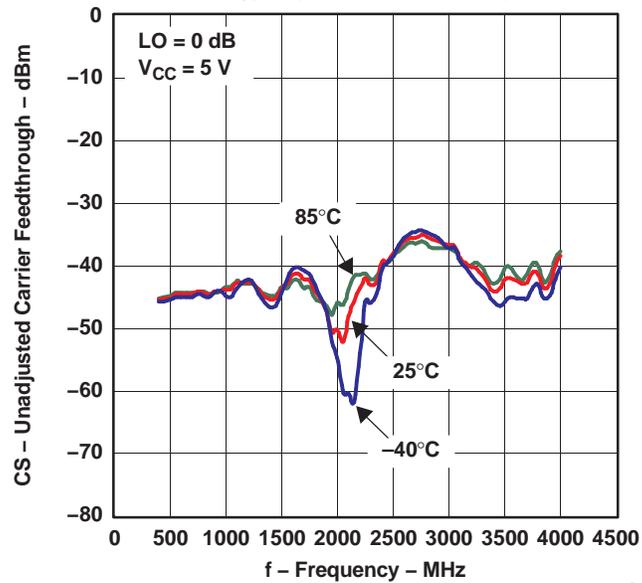


Figure 25.

G026

## APPLICATION INFORMATION AND EVALUATION BOARD

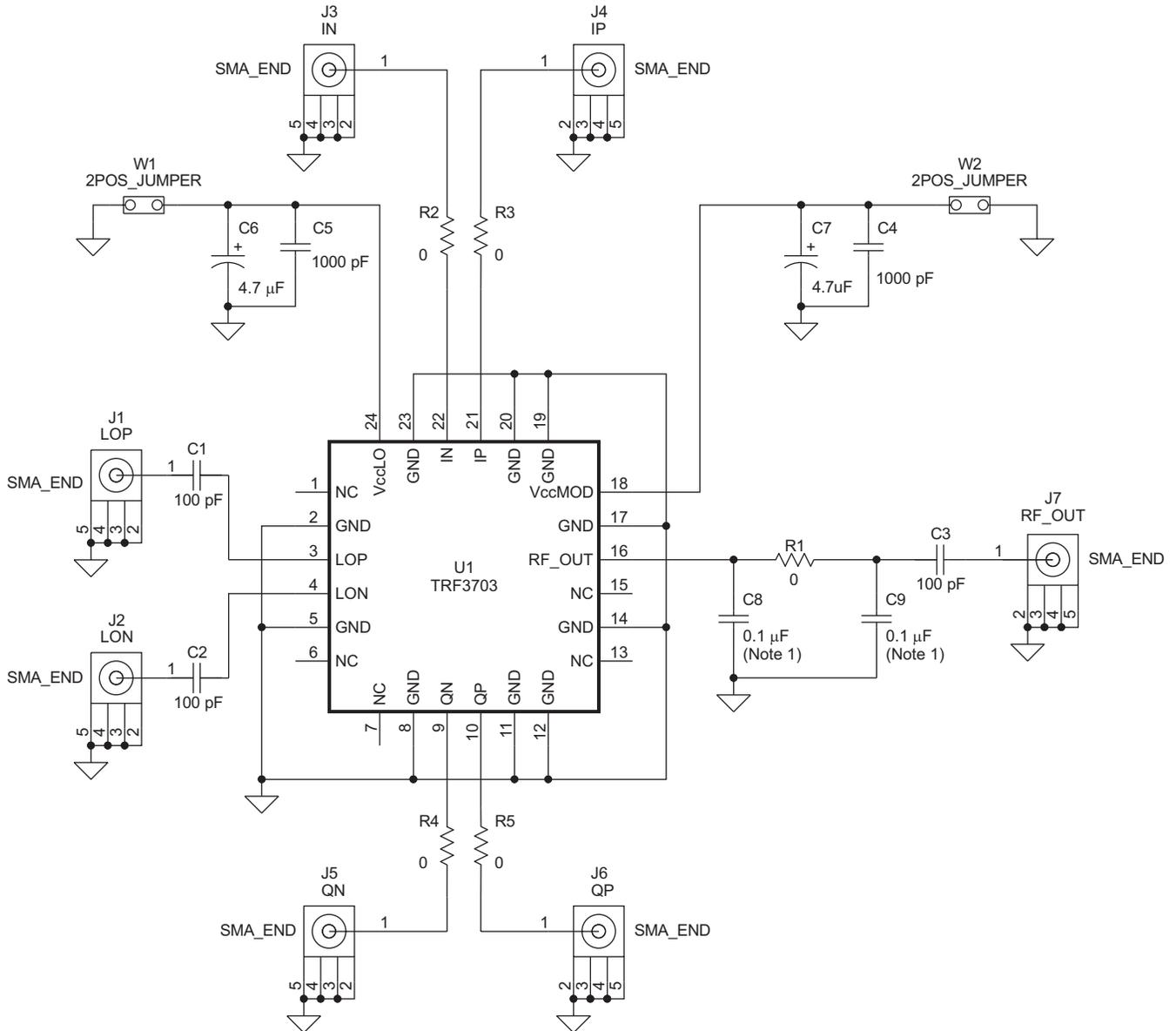
### Basic Connections

- See [Figure 26](#) for proper connection of the TRF3703315 and TRF370333 modulator.
- Connect a single power supply (4.5 V–5.5 V) to pins 18 and 24. These pins should be decoupled as shown on pins 4, 5, 6, and 7.
- Connect pins 2, 5, 8, 11, 12, 14, 17, 19, 20, and 23 to GND.
- Connect a single-ended LO source of desired frequency to LOP (amplitude between –5 dBm and 12 dBm). This should be ac-coupled through a 100-pF capacitor.
- Terminate the ac-coupled LON with 50  $\Omega$  to GND.
- Connect a baseband signal to pins 21 = I, 22 =  $\bar{I}$ , 10 = Q, and 9 =  $\bar{Q}$ .
- The differential baseband inputs should be set to the proper level, 3.3 V for the TRF370333 or 1.5 V for the TRF370315.
- RF\_OUT, pin 16, can be fed to a spectrum analyzer set to the desired frequency, LO  $\pm$  baseband signal. This pin should also be ac-coupled through a 100-pF capacitor.
- All NC pins can be left floating.

### ESD Sensitivity

RF devices may be extremely sensitive to electrostatic discharge (ESD). To prevent damage from ESD, devices should be stored and handled in a way that prevents the build-up of electrostatic voltages that exceed the rated level. Rated ESD levels should also not be exceeded while the device is installed on a printed circuit board (PCB). Follow these guidelines for optimal ESD protection:

- Low ESD performance is not uncommon in RF ICs; see the [Absolute Maximum Ratings](#) table. Therefore, customers' ESD precautions should be consistent with these ratings.
- The device should be robust once assembled onto the PCB **unless** external inputs (connectors, etc.) directly connect the device pins to off-board circuits.



S0214-01

(1) Do not install.

**Figure 26. TRF3703 EVM Schematic**

Figure 27 shows the top view of the TRF3703 EVM board.

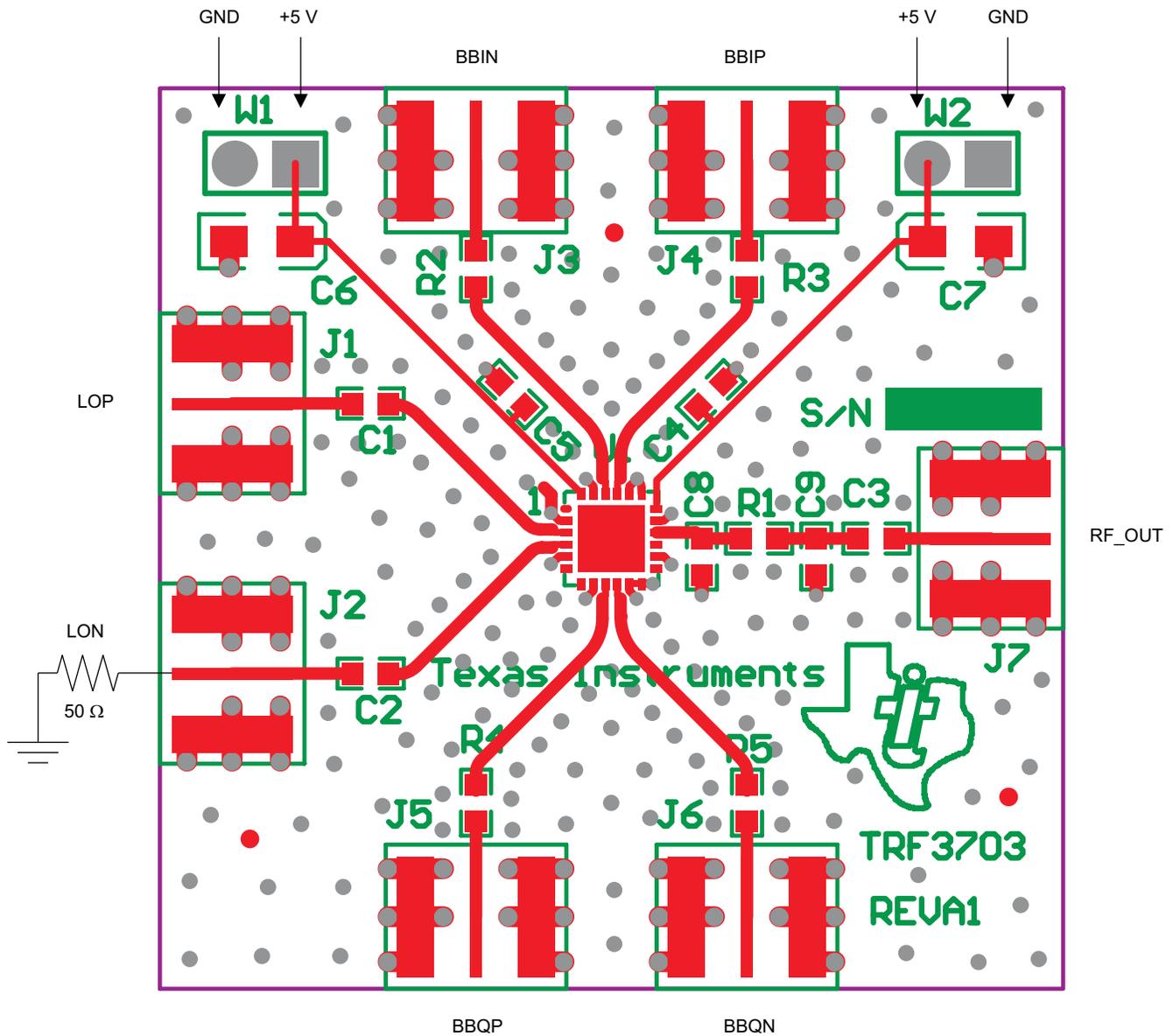


Figure 27. TRF3703 EVM Board Layout

Table 1. Bill of Materials for TRF3703 EVM

Value	Footprint	QTY	Part Number	Vendor	Digi-Key Number	REF DES	Not Installed
Tantalum 4.7- $\mu$ F, 10-V, 10% capacitor	3216	2	T491A475K010AS	KEMET	399-1561-1-ND	C6, C7	
1000-pF, 50-V, 5% capacitor	603	2	ECJ-1VC1H102J	Panasonic	PCC2151CT-ND	C4, C5	
100-pF, 50-V, 5% capacitor	603	3	ECJ-1VC1H101J	Panasonic	PCC101ACVCT-ND	C1, C2, C3	
Capacitor	603	0					C8, C9
0- $\Omega$ resistor, 1/10-W, 5%	603	5	ERJ-3GEY0R00V	Panasonic	P0.0GCT-ND	R1, R2, R3, R4, R5	

**Table 1. Bill of Materials for TRF3703 EVM (continued)**

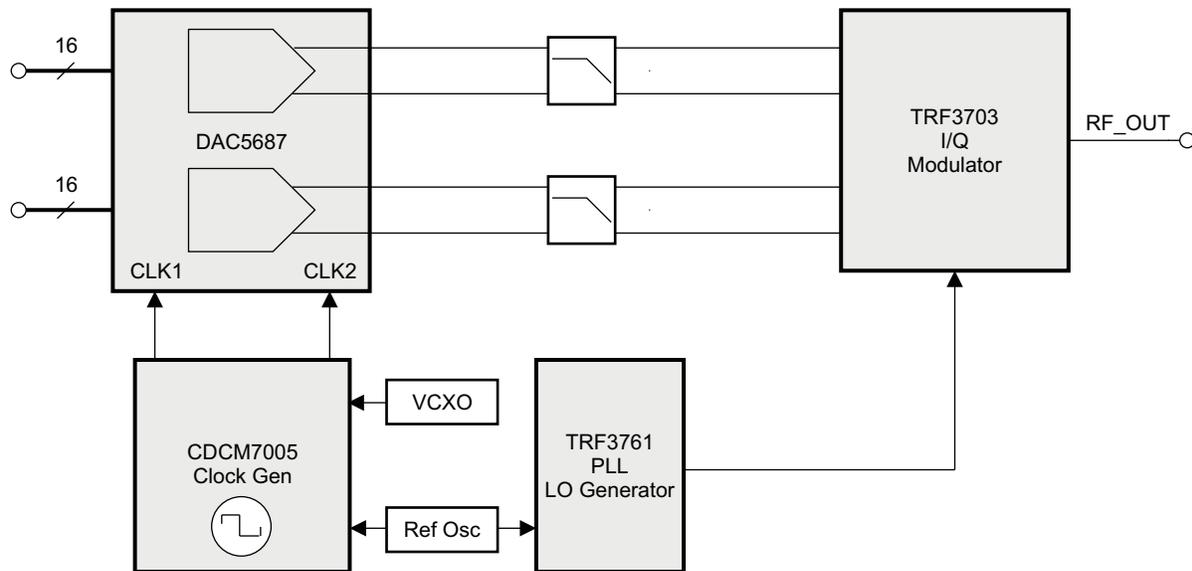
Value	Footprint	QTY	Part Number	Vendor	Digi-Key Number	REF DES	Not Installed
TRF3703	24-QFN-PP-4X4MM	1		TI		U1	
SMA connectors	SMA_END_SMALL	6	16F3627	Newark	142-0711-821	J1, J2, J3, J4, J5, J6, J7	
2POS_HEADER	2POS_JUMP	2	HTSW-150-07-L-S	SAMTEC	N/A	W1, W2	

### GSM Applications

The TRF370315 and TRF370333 are suited for GSM applications because of the high linearity and low noise level over the entire recommended operating range. These devices also have excellent EVM performance, which makes them ideal for the stringent GSM/EDGE applications.

### WCDMA Applications

The TRF370315 and TRF370333 are also optimized for WCDMA applications where both adjacent-channel power ratio (ACPR) and noise density are critically important. Using Texas instruments' DAC568X series of high-performance digital-to-analog converters as depicted in [Figure 28](#), excellent ACPR levels were measured with one-, two-, and four-WCDMA carriers. See *Electrical Characteristics*,  $f_{LO} = 2140$  MHz for exact ACPR values.



B0176-01

**Figure 28. Typical Transmit Setup Block Diagram**

## DEFINITION OF SPECIFICATIONS

### Unadjusted Carrier Feedthrough

This specification measures the amount by which the local oscillator component is attenuated in the output spectrum of the modulator relative to the carrier. This further assumes that the baseband inputs delivered to the pins of the TRF370315 and TRF370333 are perfectly matched to have the same dc offset (VCM). This includes all four baseband inputs: I,  $\bar{I}$ , Q, and  $\bar{Q}$ . This is measured in dBm.

### Adjusted (Optimized) Carrier Feedthrough

This differs from the unadjusted suppression number in that the baseband input dc offsets are iteratively adjusted around their theoretical value of VCM to yield the maximum suppression of the LO component in the output spectrum. This is measured in dBm.

### Unadjusted Sideband Suppression

This specification measures the amount by which the unwanted sideband of the input signal is attenuated in the output of the modulator, relative to the wanted sideband. This further assumes that the baseband inputs delivered to the modulator input pins are perfectly matched in amplitude and are exactly 90° out of phase. This is measured in dBc.

### Adjusted (Optimized) Sideband Suppression

This differs from the unadjusted sideband suppression in that the baseband inputs are iteratively adjusted around their theoretical values to maximize the amount of sideband suppression. This is measured in dBc.

### Suppressions Overtemperature

This specification assumes that the user has gone through the optimization process for the suppression in question, and set the optimal settings for the I, Q inputs. This specification then measures the suppression when temperature conditions change after the initial calibration is done.

Figure 29 shows a simulated output and illustrates the respective definitions of various terms used in this data sheet. The graph assumes a baseband input of 50 kHz.

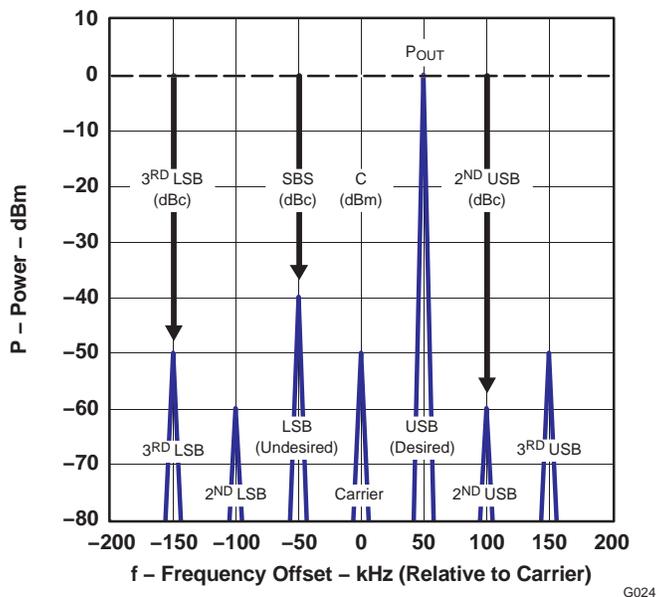


Figure 29. Graphical Illustration of Common Terms

[查询 TRF370315 数据手册](#)

## REVISION HISTORY

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision H (January, 2010) to Revision I	Page
• Changed document title to reflect 0.35-GHz minimum operating level .....	1
• Updated <i>Description</i> section to reflect 350-MHz minimum operation .....	1
• Changed LO frequency range minimum specification from 0.4 GHz to 0.35 GHz .....	4
• Added <i>Electrical Characteristics</i> table for $f_{LO} = 350$ -MHz performance data .....	4

Changes from Revision G (December, 2009) to Revision H	Page
• Added electrostatic discharge parameters to Absolute Maximum Ratings table .....	3
• Added <i>ESD Sensitivity</i> section .....	15

**PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
TRF370315IRGER	ACTIVE	VQFN	RGE	24	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TRF370315IRGET	ACTIVE	VQFN	RGE	24	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TRF370333IRGER	ACTIVE	VQFN	RGE	24	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TRF370333IRGERG4	ACTIVE	VQFN	RGE	24	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TRF370333IRGET	ACTIVE	VQFN	RGE	24	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TRF370333IRGETG4	ACTIVE	VQFN	RGE	24	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

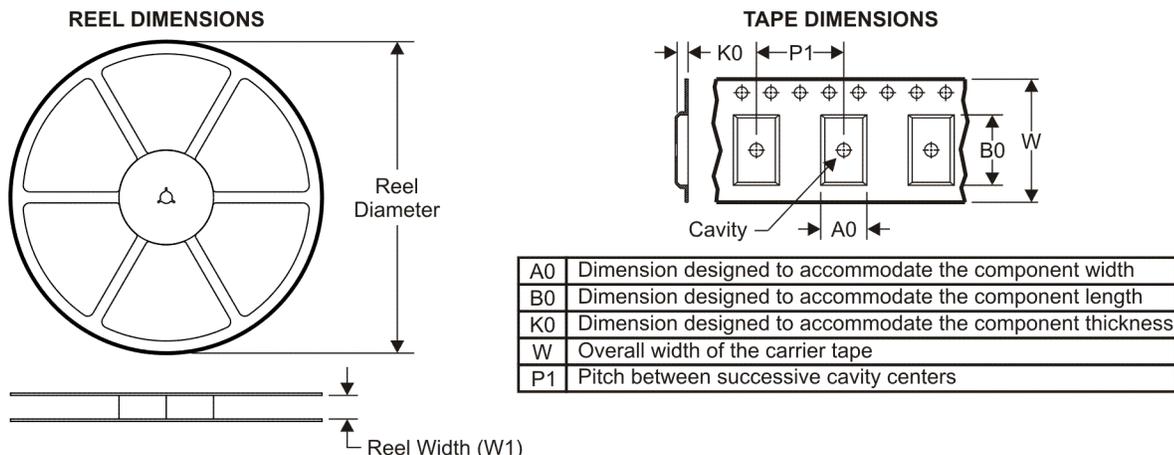
**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

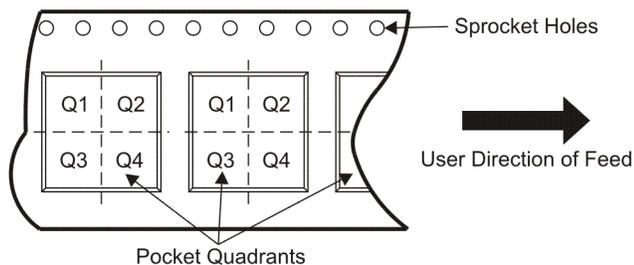
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TAPE AND REEL INFORMATION



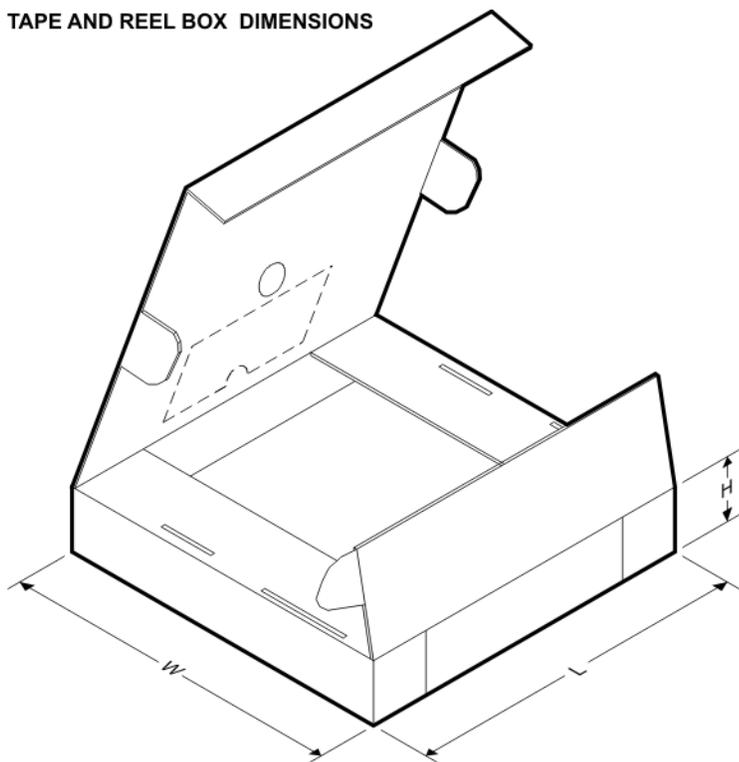
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TRF370315IRGER	VQFN	RGE	24	3000	330.0	12.4	4.3	4.3	1.5	8.0	12.0	Q1
TRF370315IRGET	VQFN	RGE	24	250	330.0	12.4	4.3	4.3	1.5	8.0	12.0	Q1
TRF370333IRGER	VQFN	RGE	24	3000	330.0	12.4	4.3	4.3	1.5	8.0	12.0	Q2
TRF370333IRGET	VQFN	RGE	24	250	330.0	12.4	4.3	4.3	1.5	8.0	12.0	Q2

**TAPE AND REEL BOX DIMENSIONS**



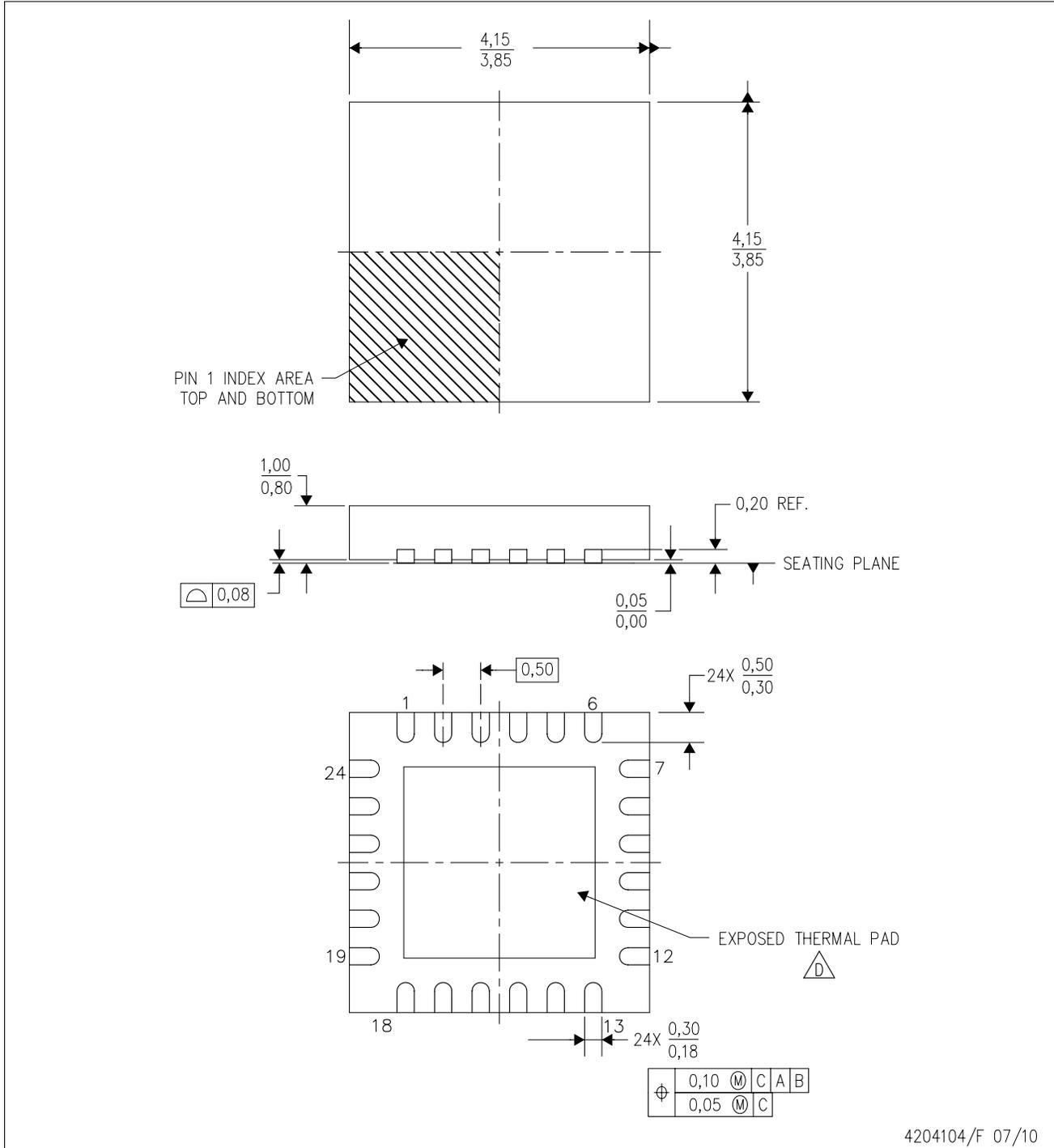
\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TRF370315IRGER	VQFN	RGE	24	3000	340.5	333.0	20.6
TRF370315IRGET	VQFN	RGE	24	250	340.5	333.0	20.6
TRF370333IRGER	VQFN	RGE	24	3000	340.5	333.0	20.6
TRF370333IRGET	VQFN	RGE	24	250	340.5	333.0	20.6

[查询"TRF370315"供应商](#)

RGE (S-PVQFN-N24)

PLASTIC QUAD FLATPACK NO-LEAD



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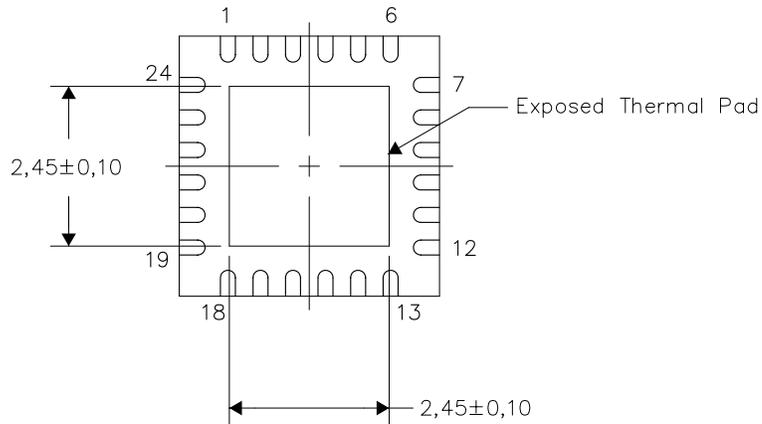
- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
  - B. This drawing is subject to change without notice.
  - C. Quad Flatpack, No-Leads (QFN) package configuration.
  -  The package thermal pad must be soldered to the board for thermal and mechanical performance. See the Product Data Sheet for details regarding the exposed thermal pad dimensions.
  - E. Falls within JEDEC MO-220.

**THERMAL INFORMATION**

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at [www.ti.com](http://www.ti.com).

The exposed thermal pad dimensions for this package are shown in the following illustration.



Bottom View

Exposed Thermal Pad Dimensions

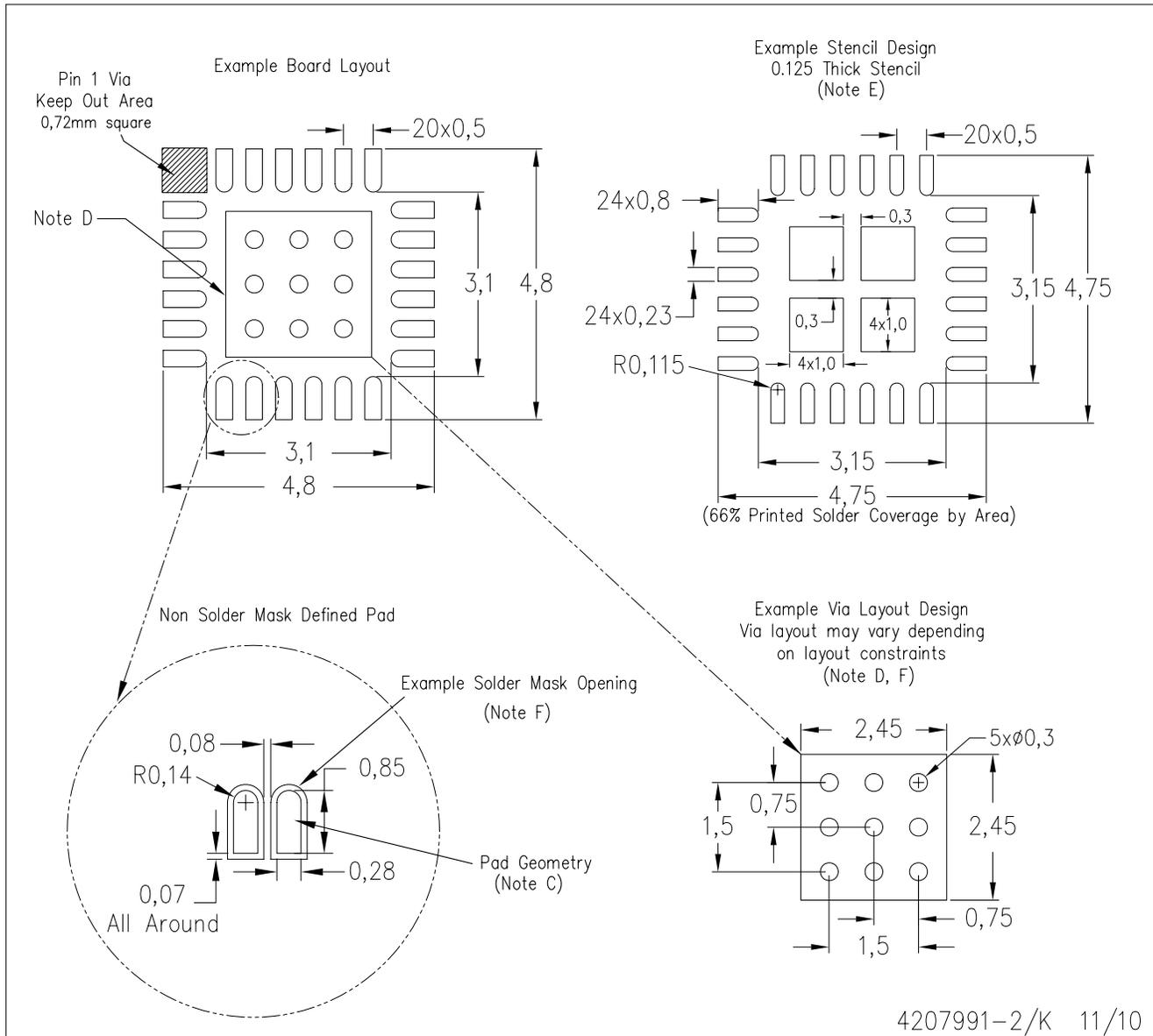
4206344-3/V 11/10

NOTES: A. All linear dimensions are in millimeters

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RGE (S-PVQFN-N24)

PLASTIC QUAD FLATPACK NO-LEAD



- NOTES:
- All linear dimensions are in millimeters.
  - This drawing is subject to change without notice.
  - Publication IPC-7351 is recommended for alternate designs.
  - This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat-Pack Packages, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at [www.ti.com](http://www.ti.com) <<http://www.ti.com>>.
  - Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
  - Customers should contact their board fabrication site for recommended solder mask tolerances and via tenting recommendations for vias placed in the thermal pad.

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DSP	<a href="http://dsp.ti.com">dsp.ti.com</a>	Computers and Peripherals	<a href="http://www.ti.com/computers">www.ti.com/computers</a>
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Interface	<a href="http://interface.ti.com">interface.ti.com</a>	Energy	<a href="http://www.ti.com/energy">www.ti.com/energy</a>
Logic	<a href="http://logic.ti.com">logic.ti.com</a>	Industrial	<a href="http://www.ti.com/industrial">www.ti.com/industrial</a>
Power Mgmt	<a href="http://power.ti.com">power.ti.com</a>	Medical	<a href="http://www.ti.com/medical">www.ti.com/medical</a>
Microcontrollers	<a href="http://microcontroller.ti.com">microcontroller.ti.com</a>	Security	<a href="http://www.ti.com/security">www.ti.com/security</a>
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RF/IF and ZigBee® Solutions	<a href="http://www.ti.com/lprf">www.ti.com/lprf</a>	Video and Imaging	<a href="http://www.ti.com/video">www.ti.com/video</a>
		Wireless	<a href="http://www.ti.com/wireless-apps">www.ti.com/wireless-apps</a>